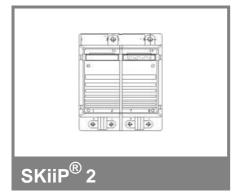
## SKiiP 232GH120-210CTV ...



# 4-pack - integrated intelligent Power System

**Power section** 

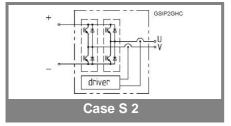
SKiiP 232GH120-210CTV

#### **Features**

- SKiiP technology inside
- Low loss IGBTs
- · CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP<sup>®</sup> 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP<sup>®</sup> 2 power section)
- with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

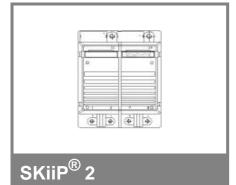
Absolute	Maximum Ratings	s = 25 °C unless otherwise specified				
Symbol	Conditions	Values	Units			
IGBT						
$V_{CES}$		1200	V			
V <sub>CES</sub> V <sub>CC</sub> 1)	Operating DC link voltage	900	V			
$V_{GES}$		± 20	V			
I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	200 (150)	Α			
Inverse diode						
I <sub>F</sub> = - I <sub>C</sub>	T <sub>s</sub> = 25 (70) °C	200 (150)	Α			
I <sub>FSM</sub>	$T_i = 150 ^{\circ}\text{C},  t_p = 10 \text{ms};  \text{sin}.$	1440	Α			
I²t (Diode)	Diode, T <sub>j</sub> = 150 °C, 10 ms	10	kA²s			
T <sub>j</sub> , (T <sub>stg</sub> )		- 40 (- 25) + 150 (125)	°C			
V <sub>isol</sub>	AC, 1 min. (mainterminals to heat sink)	3000	V			

<b>Characteristics</b> $T_s = 25$ °C unless otherwise specified									
Symbol	Conditions				min.	typ.	max.	Units	
IGBT									
$V_{CEsat}$	I <sub>C</sub> = 175 A	, T <sub>i</sub> = 25 (1	25) °C			2,6 (3,1)	3,1	V	
V <sub>CEO</sub>	$T_i = 25 (12)$					1,2 (1,3)	1,5 (1,6)	V	
r <sub>CE</sub>	$T_{i} = 25 (12)$					7,5 (10)	9 (11,5)	mΩ	
I <sub>CES</sub>	$V_{GE} = 0 V$	V <sub>CE</sub> = V <sub>CE</sub>	S,			10	0,4	mA	
	$T_i = 25 (12)$	25) °C							
E <sub>on</sub> + E <sub>off</sub>	I <sub>C</sub> = 175 A, V <sub>CC</sub> = 600 V						53	mJ	
on on	T <sub>j</sub> = 125 °C						93	mJ	
R <sub>CC' + EE'</sub>	terminal ch	terminal chip, T <sub>i</sub> = 125 °C				0,5		mΩ	
L <sub>CE</sub>	top, botton	n <sup>′</sup>				15		nΗ	
C <sub>CHC</sub>	per phase	, AC-side				1,4		nF	
Inverse o	diode								
$V_F = V_{EC}$	I <sub>F</sub> = 150 A	, T <sub>i</sub> = 25 (1	25) °C			2,1 (1,9)	2,6	V	
	$T_i = 25 (12)$	25) °C				1,3 (1)	1,4 (1,1)	V	
r <sub>T</sub>	$T_{j} = 25 (12)$					5 (6)	6,8 (7,8)	mΩ	
E <sub>rr</sub>	$I_{\rm C} = 175  {\rm A}$	$V_{CC} = 600$	) V				6	mJ	
	$T_{j} = 125 °C$	$C, V_{CC} = 90$	00 V				8	mJ	
Mechani	cal data								
M <sub>dc</sub>	DC termina	als, SI Unit	s		6		8	Nm	
$M_{ac}$	AC terminals, SI Units				13		15	Nm	
W	SKiiP® 2 System w/o heat sink					1,9		kg	
w	heat sink					4,7		kg	
			P16 hea	t sink; 3′	10m <sup>3</sup> /h);	" <sub>r</sub> " refer	ence to		
temperat		or			1	-		1	
R <sub>th(j-s)I</sub>	per IGBT						0,129	K/W	
$R_{th(j-s)D}$	per diode						0,375	K/W	
R <sub>th(s-a)</sub>	per module						0,044	K/W	
$Z_{th}$	R <sub>i</sub> (mK/W) (max. values)				i .	tau <sub>i</sub> (s)			
_	1	2	3	4	1	2	3	4	
Z <sub>th(j-r)I</sub>	14	99	15 45		1	0,13	0,001		
Z <sub>th(j-r)D</sub>	41	289	45		1	0,13	0,001		
$Z_{th(r-a)}$	14,2	19,3	6,8	3,7	262	50	5	0,02	



This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee, expressed or implied is made regarding delivery, performance or suitability.

### SKiiP 232GH120-210CTV ...



## 4-pack - integrated intelligent Power System

4-pack integrated gate driver

SKiiP 232GH120-210CTV

#### **Gate driver features**

- · CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current ,heat sink temperature and DC-bus voltage(option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- · Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP<sup>®</sup> 2 gate driver)

Absolute Maximum Ratings					
Symbol	Conditions	Values	Units		
V <sub>S1</sub> V <sub>S2</sub>	stabilized 15 V power supply unstabilized 24 V power supply	18 30	V V		
$V_{iH}$	input signal voltage (high)	15 + 0,3	V		
	secondary to primary side input / output (AC, r.m.s., 2s ) output 1 / output 2 (AC, r.m.s., 2s ) switching frequency operating / storage temperature	75 3000 1500 20 - 25 + 85	kV/µs Vac Vac kHz °C		

Characte	(T <sub>a</sub> = 25			= 25 °C)	
Symbol	Conditions	min.	typ.	max.	Units
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
I <sub>S1</sub>	V <sub>S1</sub> = 15 V	230+230	230+230*f/f <sub>max</sub> +1,3*(I <sub>AC</sub> /A)		
I <sub>S2</sub>	V <sub>S2</sub> = 24 V	170+280*f/f <sub>max</sub> +1,0*(I <sub>AC</sub> /A)			mA
V <sub>iT+</sub>	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)			5,4	V
R <sub>IN</sub>	input resistance		10		kΩ
t <sub>d(on)IO</sub>	input-output turn-on propagation time		1,2		μs
t <sub>d(off)IO</sub>	input-output turn-off propagation time		1,6		μs
tpERRRESET	error memory reset time	9			μs
t <sub>TD</sub>	top / bottom switch : interlock time		2,3		μs
I <sub>analogOUT</sub>	8 V corresponds to max. current of 15 V supply voltage		200		Α
l,	(available when supplied with 24 V)			50	mA
Vs1outmax	output current at pin 15/16/18/19			5	mA
V <sub>0I</sub>	logic low output voltage			0.6	V
V <sub>OH</sub>	logic high output voltage			30	V
I <sub>TRIPSC</sub>	over current trip level (I <sub>analog OUT</sub> = 10 V)		250		Α
I <sub>TRIPLG</sub>	ground fault protection		58		A
T <sub>tp</sub>	over temperature protection	110		120	°C
	trip level of U <sub>DC</sub> -protection	900			V
U <sub>DCTRIP</sub>	( U <sub>analog OUT</sub> = 9 V); (option)	300			v

For electrical and thermal design support please use SEMISEL. Access to SEMISEL is via SEMIKRON website http://www.semikron.com.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee, expressed or implied is made regarding delivery, performance or suitability.

